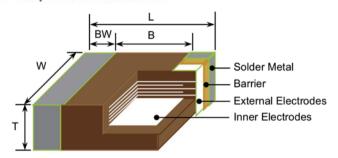


The Multilayer Ceramic Chip Capacitors supplied in bulk, cassette or taped & reel package are ideally suitable for thick-film Hybrid circuits and automatic surface mounting on printed circuit boards.

Mainly used in electric circuit for by-pass, filtering and smoothing circuit.

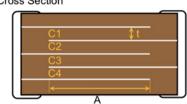
Shapes and Dimensions



Dimension (mm) [inches]

EIA style	L	W	Tmax.	BWmin	Bmin.
0201	0.60±0.03	0.30±0.03	0.33	0.10	0.20
	[.024±.002]	[.011±.002]	[.013]	[.004]	[.008]
0402	1.00±0.05	0.50±0.05	0.55	0.15	0.30
	[.039±.002]	[.020±.002]	[.022]	[.006]	[.012]
0603	1.60±0.10	0.80±0.10	1.00	0.15	0.40
	[.063±.004]	[.031±.004]	[.039]	[.006]	[.016]
0805	2.00±0.20	1.25±0.20	1.45	0.20	0.70
	[.079±.008]	[.049±.008]	[.057]	[.008]	[.028]
1206	3.20±0.30	1.60±0.20	1.80	0.30	1.50
	[.126±.012]	[.063±.008]	[.071]	[.012]	[.059]
1210	3.20±0.30	2.50±0.20	2.60	0.30	1.60
	[.126±.012]	[.098±.008]	[.102]	[.012]	[.063]
1808	4.60±0.30	2.00±0.20	2.20	0.30	2.50
	[.181±.012]	[.079±.008]	[.087]	[.012]	[.098]
1812	4.60±0.30	3.20±0.30	3.00	0.30	2.50
	[.181±.012]	[.126±.012]	[.118]	[.012]	[.098]
1825	4.60±0.30	6.35±0.40	3.40	0.30	2.50
	[.181±.012]	[.250±.016]	[.118]	[.012]	[.098]
2208	5.70±0.40	2.00±0.20	2.20	0.30	3.50
	[.220±.016]	[.197±.008]	[.087]	[.012]	[.137]
2211	5.70±0.40	2.80±0.40	3.00	0.30	3.50
	[.220±.016]	[.110±.016]	[.118]	[.012]	[.137]
2220	5.70±0.40	5.00±0.40	3.40	0.30	3.50
	[.220±.016]	[.197±.016]	[.133]	[.012]	[.137]
2225	5.70±0.40	6.35±0.40	3.40	0.30	3.50
	[.220±.016]	[.250±.016]	[.133]	[.012]	[.137]

Cross Section



$$C = \varepsilon_0 \cdot \varepsilon$$
 $A \cdot N$

C : Capacitance

 ϵ_0 : Dielectric constant in the air

 ϵ : Proportional dielectric constant

A : Overlap Area

t : Dielectric Thickness

N: Layers

Nominal Capacitance and Tolerance

1. Standard Combination of Nominal Capacitance and Tolerance

IP0 X7R	J (±5%),K (±10%)	E-12
X7R	IC(±400() N4(±000()	
	K(±10%), M(±20%)	E-3,E-6 E-12 Series
X7T	K(±10%), M(±20%)	E-3,E-6 Series
X7P	K(±10%), M(±20%)	E-3,E-6 Series
X6S	K(±10%), M(±20%)	E-3,E-6 Series
X5R	K(±10%), M(±20%)	E-3,E-6 Series
	X7P X6S	X7P K(±10%), M(±20%) X6S K(±10%), M(±20%)

2. E Series (Standard Number)

		1				-,						
E-		Application Capacitance										
Series												
E-3		<u>1</u>	.0			<u>2</u> .	2			4.7	7	
E-6	1	.0	<u>1.</u>	5	2.	2	<u>3</u> .	3	<u>4</u> .	7	6.	8
E12	1.0	1.2	1.5	1.8	2.2	2.7	3.3	3.9	<u>4.7</u>	5.6	6.8	8.2





♦EIA Designations

For Class I Dielectrics

Coefficie capacita (ppm/ °C	nce	Multiplier a to column	pplicable	Tolerance coeff.(pp	e of temp. m/ ℃)
0.0	С	-1.0	0	30	G
1.0	M	-10	1	60	Н
1.5	Р	-100	2	120	J
2.2	R	-1000	3	250	K
3.3	S	-10000	4	500	L
4.7	Т	+1	5	1000	M
7.5	U	+10	6	2500	N
		+100	7		
		+1000	8		
		+10000	9		

For Class Π Dielectrics

Low Temp. Symbol	High Temp. Symbol	Max. %△C Symbol	
-55℃ X	+45℃ 3	±1.0%	Α
-30°C Y	+65°C 4	±1.2%	В
+10℃ Z	+85℃ 5	±2.2%	С
	+105℃ 6	±3.3%	D
	+125℃ 7	±4.7%	E
	+150 ℃ 8	±7.5%	F
	+200 ℃ 9	±10.0%	Р
		±15.0%	R
		±22.0%	S
		+22% /-33%	Т
		+22% /-56%	U
		+22% /-82%	V

Ex.: C0G Negative U2J Negative

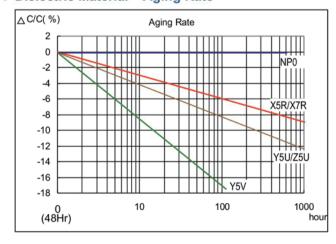
0±30ppm/ °C 750±120ppm/ °C

Ex.: X7R $-55 \sim +125 \,^{\circ}\text{C}$ $\pm 15\%$ Y5V $-30 \sim +85 \,^{\circ}\text{C}$ +22%/-82%

♦Operating Temperature Range

Class	EIA Symbol	Dielectric Code	Temperature Range(℃)	Capacitance Change	Reference Temperature
1	NP0	N	-55℃ ~ +125 ℃	0±30 ppm/°C	25 ℃
	SL	L	-25°C ~ +85 °C	+350/-1000 ppm/°C	25℃
П	X7R	X	-55°C ~ +125°C	±15%	25 ℃
	X6S	S	-55°C ~ +105°C	±22%	25 ℃
	X7P	Р	-55°C ~ +125°C	±10%	25℃
	X7T	Т	-55°C ~ +125°C	+22% /-33%	25 ℃
	X7S	R	-55℃ ~ +125℃	±22%	25 ℃
	X5R	В	-55℃ ~ +85℃	±15%	25℃

◆ Dielectric Material – Aging Rate



Aging Rate NP0: 0

X7R/X5R : 1 ~ 4 % / decade Y5U/Z5U : 4~6% / decade Y5V : 6~10 % / decade

After performing De-Aging at 150±5 $^{\circ}\!\mathrm{C}$ for 30 minutes and

Placement at room temperature for 48 hours.





Item	Specification	Test Conditions			
Operating Temperature	Char. Operating Temp. NP0(N) -55°~ +125°C X7R (X) -55°C~ +125°C X5R (B) -55°C~ +85°C X7P (P) -55°C~+125°C X7T(T) -55°C~+125°C X6S (S) -55°C~+105°C				
	No abnormal exterior appearance	Visual Inspection			
Capacitance	Within the specified tolerance	Char. Frequency Voltage NP0			
Quality Factor	Class I (NP0): More Than 30pF : Q ≧1000 30pF & Below: Q≧400+20C (C: Cap., pF)	C≤1000pF 1MHz±10% 1.0±0.2Vrms C>1000pF 1KHz±10%			
Dissipation Factor	Class II (X7R/X5R/X7P/X7T/X6S): Please check the summery of specification of each product series	C \leq 10uF 1KHz±10% 1.0±0.2Vrms 0.5±0.2Vrms C >10uF 120Hz±20% 0.5±0.2Vrms Perform a heat temperature at 150±5 $^{\circ}$ C for 30min. then place at room temp. for 24±2hrs.			
Insulation Resistance	10,000MΩ or 500/C Ω, whichever is smaller for rated voltage>10V and greater 100/C Ω for rated voltage≤10V.	Applied voltage: rated voltage Charge time: 60±5 sec. Charge-discharge current shall be less than 50mA current.			
	$X1/Y2$ and $X2$: $10G\Omega$ min	Applied voltage: 500V charge time 60 sec			
Dielectric Withstand Voltage (DWV) (Unless otherwise stated on product descriptions)	No dielectric breakdown or mechanical breakdown X1/Y2 and X2	200% /150%/120%/100% Rated Voltage For information which product has which applied voltage, please contact with HEC sales representative. Voltage ramp up rate ≤ 500v/sec 1~5 sec. charge/discharge Current is less than 50mA. ※ Withstanding voltage testing requires immersion of the element in a isolation fluid prevarcing on the chip surface, at voltage over 1000X Capacitor: Applied Voltage 1075Vdc(4.3Ur) Y Capacitor: Applied Voltage 1500Vac For 1 Min. Current limited to less than 50mA			
Temperature Capacitance Coefficient	Char. Temp. Range Cap. Change NP0(N) -55°C~+125°C ± 30ppm/°C X7R (X) -55°C~+125°C ± 15% X5R (B) -55°C~+85°C ± 15% X7P (P) -55°C~+125°C ± 10% X7T(T) -55°C~+125°C + 22%/-33% X6S (S) -55°C~+105°C ± 22%	ClassI: [C2-C1/C1(T2-T1)] × 100% Class II: (C2-C1)/C1 × 100% T1:Standard temperature(25°C) T2:Test temperature C1:Capacitance at standard temperature C2:Capacitance at test temperature			
Adhesive Strength of Termination	No indication of peeling shall occur on the terminal electrode.	≤ 0603 size : 5N(≒ 0.5 Kg· > 0603 size : 10N(≒1.0 Kg· pull force shall be applied for			



pull force shall be applied for

10±1 sec.



Specifications & Test Conditions

Item		Specification	Test Conditions
Resistance to Flexure of Substrate	No mechanica	al damage or capacitance than the following table. Capacitance Change $\leq \pm 5.0\%$ of initial value $\leq \pm 12.5\%$ of initial value	The board should bend 1.0mm with a rate of 1.0mm/sec. R230 Bending Limit Limit
Solderability		% of the termination surface dered so the metal part does not issolve .	Solder Temperature : 245±5°C Dip Time : 5 ± 0.5 sec. Immersing Speed : 25±10% mm/s Solder : Lead Free Solder Flux : Rosin Preheat : At 80~120 °C For 10~30 sec.
Resistance to Soldering Heat Appearance No mechanical damage shall occur Capacitance Class I (NP0): Within 2.5% or ±0.25pF, whichever is larger of initial value Class II: Char. Cap. change X7R(X) Within ± 10% X5R(B) Within ± 10% X7P(P) Within ± 10% X7T(T) Within ± 10% X6S (S) Within ± 10% Q / Tanδ To satisfy the specified initial value Val		Class II capacitor shall be set for 48± 4 hours a room temperature after one hour heat treatment at 150 ±0/-10°C before initial measuring. Preheat: at 150±10°C for 60~120sec. Dip: solder temperature of 260±5°C Dip Time: 10 ± 1sec. Immersing Speed: 25±10% mm/s Flux: Rosin Measure at room temperature after cooling for Class I: 24 ± 2 Hours Class II: 48 ± 4 Hours	
	Insulation Resistance	To satisfy the specified initial value	Class II capacitor shall be set for 48±4 hours
Temperature	Appearance	No mechanical damage shall	Olass II Capacitor shall be set for 40±4 flours

Cycle

occur

Capacitance Class I (NP0):

Within 2.5% or ±0.25pF,

whichever is larger of initial value

Char.	Cap. change
X7R(X)	Within ± 7.5%
X5R(B)	Within ± 7.5%
X7P(P)	Within ± 7.5%
X7T(T)	Within ± 7.5%
X6S(S)	Within ± 7.5%

To satisfy the specified initial Q / Tanδ Insulation To satisfy the specified initial

Resistance value at room temperature after one hour heat treatment at 150 +0/-10 °C before initial measuring.

Capacitor shall be subjected to five cycles of the temperature cycle as following:

Temp.(℃)	Time(min)
Min Rated Temp.+0/-3	30
25	3
Max Rated Temp.+3/-0	30
25	3
	Min Rated Temp.+0/-3 25 Max Rated Temp.+3/-0

Measure at room temperature after cooling for

Class I: 24 ± 2 Hours Class II: 48 ± 4 Hours





Specifications	& Test Cor	nditions	
Item		Specification	Test Conditions
Humidity	Appearance	No mechanical damage shall occur	Class II capacitor shall be set for 48±4 hours at room temperature after one hour heat treatment at 150 +0/-10 °C before initial measure.
	Capacitance	Class I NP0: Within 5.0% or ±0.5pF, whichever is larger of initial value Class II: Char. Cap. change X7R(X) Within ± 15% X5R(B) Within ± 15% X7P(P) Within ± 15% X7T(T) Within ± 15% X6S(S) Within ± 15%	Temperature : 40 ± 2 °C Relative humidity : $90\sim95\%$ RH Test Time : $500\pm12/-0$ hr Measure at room temperature after cooling for Class I : 24 ± 2 Hours Class II : 48 ± 4 Hours
	Q Class I	30pF & over : Q ≥350 10 to 30pF : Q≥275+2.5C 30pF & below: Q≥200+10C	
	Tanδ Class II	please contact with HEC sales	
	Insulation Resistance	1,000M Ω or 50/C Ω , whichever is smaller for rated voltage>10V and greater 10/C Ω for rated voltage \leq 10V. (C in Farad)	
High Temperature Load	Appearance	No mechanical damage shall occur	Class II capacitors applied DC voltage (following table) is applied for one hour at maximum operation temperature $\pm 3^{\circ}$ C then shall be set for
(Life Test)	Capacitance	Class I NP0: Within 5.0% or ±0.5pF, whichever is larger of initial value Class II: Char. Cap. change X7R(X) Within ± 15%	48±4 hours at room temperature and the initial measurement shall be conducted. Applied Voltage:
		X5R(B) Within ± 15% X7P(P) Within ± 15% X7T(T) Within ± 15% X6S(S) Within ± 15%	For information which product has which applied voltage, please contact with HEC sales representative
	Q Class I	30pF & Over : Q ≧350 10 to 30pF : Q≧275+2.5C 30pF & Below: Q≧200+10C	Temperature: max. operating temperature Test Time: 1000 +48/-0Hr Current applied: 50 mA max.
	Tanδ Class II	please contact with HEC sales	Max. Measure at room temperature after cooling
	Insulation Resistance	1,000M Ω or 50/C $\Omega,$ whichever is smaller	for Class I : 24 \pm 2 Hours Class II : 48 \pm 4 Hours





Specifications & Test Conditions

Item		Specification	Test Conditions
Vibration	Appearance	No mechanical damage shall occur	Solder the capacitor on P.C. board. Vibrate the capacitor with an amplitude of
	Capacitance	Within the specified tolerance	1.5mm P-P changing the frequencies from 10Hz to 55Hz and back to 10Hz
	Q / Tanδ	To satisfy the specified initial	in about 1 min.
		value	Repeat this for 2 hours each in 3 perpendicular directions.





Specifications & Test Conditions					
Item	Specification	Test Conditions			
Operating Temperature	Char. Operating Temp. NP0(N) -55°∼ +125°C X7R (X) -55°C∼ +125°C X7S (R) -55°C∼ +125°C X5R (B) -55°C∼ +85°C X6S (S) -55°C∼ +105°C				
Visual	No abnormal exterior appearance	Visual Inspection			
Capacitance	Within the specified tolerance	Char. Frequency Voltage NP0			
Quality Factor	Class I (NP0): More Than 30pF : Q \geq 1000 30pF & Below: Q \geq 400+20C (C: Cap., pF)	C≤1000pF 1MHz±10% 1.0±0.2Vrms C>1000pF 1KHz±10%			
Dissipation Factor	Class II (X7R/X5R/X7P/X7T/X7S/X6S): Please check the summery of specification of each product series	C \leq 10uF 1KHz \pm 10% 1.0 \pm 0.2Vrms 0.5 \pm 0.2Vrms C >10uF 120Hz \pm 20% 0.5 \pm 0.2Vrms Perform a heat temperature at 150 \pm 5°C for 30min. then place at room temp. for 24 \pm 2hrs.			
Insulation Resistance	10,000MΩ or 500/C Ω, whichever is smaller for rated voltage>10V and greater 100/C Ω for rated voltage≤10V.	Applied Voltage: Rated Voltage Charge Time: 60±5 sec. Charge-Discharge current shall be les than 50mA current			
Dielectric Withstand Voltage (DWV) (Unless otherwise stated on product descriptions)	No dielectric breakdown or mechanical breakdown	250% of the rated voltage for 1~5 sec. charge/discharge Current is less than 50mA			
Temperature Capacitance Coefficient	Char. Temp. Range Cap. Change NP0(N) -55°C~+125°C ± 30ppm/°C X7R (X) -55°C~+125°C ± 15% X7S (R) -55°C~+125°C ± 22% X5R (B) -55°C~+85°C ± 15% X6S (S) -55°C~+105°C ± 22%	ClassI: [C2-C1/C1(T2-T1)] × 100% Class II: (C2-C1)/C1 × 100% T1:Standard temperature(25°C) T2:Test temperature C1:Capacitance at standard temperature C2:Capacitance at test temperature 0.2Vrms shall be applied.			
Adhesive Strength	No indication of peeling shall occur on the				

Adhesive Strength of Termination

No indication of peeling shall occur on the terminal electrode.



 $\stackrel{\leq}{=} 0603 \text{ size} : 5\text{N}(\ \stackrel{=}{=}\ 0.5 \text{ Kg} \cdot \text{f}) \\ > 0603 \text{ size} : 10\text{N}(\ \stackrel{=}{=}\ 1.0 \text{ Kg} \cdot \text{f})$

pull force shall be applied for 10 ± 1 sec.





Specifications & Test Conditions

Item	Specification	Test Conditions
Resistance to Flexure of Substrate	No mechanical damage or capacitance change more than the following table. Char. Capacitance Change NP0(N) $\leq \pm 5.0\%$ of initial v X7R (X) $\leq \pm 12.5\%$ of initial v X5R (B) $\leq \pm 12.5\%$ of initial v X6S (S) $\leq \pm 12.5\%$ of initial v	alue alue alue 45±1mm 45±1mm
Solderability	More than 90% of the termination surface should be soldered so the metal part doe come out or dissolve .	_, _, _, _, _,
Resistance to Soldering Heat	Appearance No mechanical damage so occur Capacitance Class I (NP0): Within 2.5% or ± 0.25 pF, whichever is larger of initia Class II: Char. Cap. change	room temperature after one hour heat treatment at 150 +0/-10°C before initial measuring. Preheat: at 150±10°C for 60~120sec. Dip: solder temperature of 260±5°C Dip Time: 10 ± 1sec. Immersing Speed: 25±10% mm/s Flux: Rosin Ilue Measure at room temperature after cooling for
	Q / Tanδ To satisfy the specified init Insulation Resistance To satisfy the specified init	
Temperature Cycle	Appearance No mechanical damage s occur Capacitance Class I (NP0): Within 2.5% or ±0.25pF, whichever is larger of initia Char. Cap. change X7R(X) Within ± 7.5% X7S(R) Within ± 7.5% X5R(B) Within ± 7.5% X6S(S) Within ± 7.5%	at room temperature after one hour heat treatment at 150 +0/-10 ℃ before initial measuring. Capacitor shall be subjected to five cycles of
	Q / Tanō To satisfy the specified init value Insulation Resistance Value	Class I : 24 ± 2 Hours Class II : 48 ± 4 Hours



Resistance

value



Specifications & Test Conditions				
Item		Specification	Test Conditions	
Humidity	Appearance	No mechanical damage shall occur Class I (NP0): Within 5.0% or ±0.5pF, whichever is larger of initial value Class II: Char. Cap. change X7R(X) Within ± 12.5% X7S(R) Within ± 12.5% X5R(B) Within ± 12.5% X6S(S) Within ± 12.5%	Class II capacitors applied DC voltage of the rated voltage is applied for one hour at maximum operation temperature then shall be set for 48± 4 hours at room temperature and the initial measurement shall be conducted. Applied Voltage :Rated Voltage Temperature : 40± 2°C Relative Humidity : 90 ~ 95%RH Test Time : 500 Hrs Max. Current Applied : 50 mA Max. Measure at room temperature after cooling for Class I : 24 ± 2 Hours	
	Q Class I	30pF & over : Q ≧350 10 to 30pF : Q≧275+2.5C 30pF & below: Q≧200+10C	Class II : 48 ± 4 Hours	
	Tanδ Class II	please contact with HEC sales		
	Insulation Resistance	1000MΩ or 50/C Ω , whichever is smaller for rated voltage>10V and greater 10/C Ω for rated voltage \leq 10V		
Damp Heat/ Steady State	Appearance	No mechanical damage shall occur	Class II capacitors applied DC voltage of the rated voltage is applied for one hour at	
(Test for the product under 100Vdc)	Capacitance	Class I (NP0): Within 7.5% or $\pm 0.75 pF$, whichever is larger of initial value Class II : Char. Cap. change X7R(X) $\leq \pm 12.5\%$ of initial value X7S(R) $\leq \pm 12.5\%$ of initial value X5R(B) $\leq \pm 12.5\%$ of initial value X6S(S) $\leq \pm 12.5\%$ of initial value	Test time: 500 +12/-0Hr	
	Q Class I	30pF & Over : Q ≥350 10 to 30pF : Q≥275+2.5C 30pF & Below: Q≥200+10C		
	Tanδ Class II	please contact with HEC sales	•	
	Insulation Resistance	$500M\Omega$ or 25/C Ω , whichever is smaller for rated voltage>10V and greater 5/C Ω for rated voltage \leq 10V. (C in Farad)		





Specifications (& Test Co	onditions
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Item		Specification	Test Conditions
High Temperature Load (Life Test)	Appearance	No mechanical damage shall occur	The capacitors applied DC testing voltage is applied for one hour at maximum operation temperature then shell be set for 48± 4 hours a room temperature and the initial measurement shall be conducted.
	Capacitance	Class I (NP0): Within 5.0% or ±0.5pF, whichever is larger of initial value Class II:	
		Char. Cap. change X7R(X) Within ± 12.5% X7S(R) Within ± 12.5%	Applied Voltage: Rated Voltage However: The class I applied voltage 200% of rated voltage.
		X5R(B)Within \pm 12.5%X6S(S)Within \pm 12.5%	Temperature: max. operation temperature Test Time: 1000 Hrs Max. Current Applied: 50mA Max
	Q Class I	30pF & Over : Q ≥ 350 10 to 30pF : Q≥ 275+2.5C 30pF & Below: Q≥ 200+10C	Measure at room temperature after cooling for Class I : 24 \pm 2 Hours Class II : 48 \pm 4 Hours
	Tanδ Class II	please contact with HEC sales	
	Insulation Resistance	1,000M Ω or 50/C Ω , whichever is smaller . For rated voltage>10V and greater 10/C Ω for rated voltage \leq 10V. (C in Farad)	
Vibration	Appearance	No mechanical damage shall	Solder the capacitor on P.C. board.
	Capacitance	Within the specified tolerance	Vibrate the capacitor with an amplitude of 1.5mm P-P changing the frequencies from 10Hz to 55Hz and back to 10Hz
	Q / Tanδ	To satisfy the specified initial value	in about 1 min. Repeat this for 2 hours each in 3 perpendicular directions.

